1. General description

PNP/PNP matched double transistor in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Current gain matching
- Base-emitter voltage matching
- Application-optimized pinout
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- · Current mirror
- Differential amplifier

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | l | Min | Тур | Max | Unit |
|------------------------------------|-------------------------------|--|---|------|-----|------|------|
| Per transist | or | | | | | | |
| V_{CEO} | collector-emitter voltage | open base | - | - | - | -45 | V |
| I _C | collector current | | - | - | - | -100 | mA |
| h _{FE} | DC current gain | V _{CE} = -5 V; I _C = -2 mA; T _{amb} = 25 °C | 2 | 200 | 290 | 450 | |
| Per device | | | | | | | |
| h _{FE1} /h _{FE2} | DC current gain matching | $V_{CE} = -5 \text{ V}; I_{C} = -2 \text{ mA}; T_{amb} = 25 \text{ °C}$ | (| 0.98 | 1 | 1.02 | |
| V _{BE1} -V _{BE2} | base-emitter voltage matching | | - | -2 | - | 2 | mV |



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5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|---------------|--------------------|-----------------------|
| 1 | B1 | base TR1 | | 04 54 50 |
| 2 | B2 | base TR2 | 6 5 4 | C1 E1 E2 |
| 3 | C2 | collector TR2 | | TR2 |
| 4 | E2 | emitter TR2 | | |
| 5 | E1 | emitter TR1 | | B1 B2 C2 006aaa550 |
| 6 | C1 | collector TR1 | TSSOP6 (SOT363) | 33334355 |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|---|---------------|
| | Name | Description | Version |
| PMP5201Y-Q | | plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body | <u>SOT363</u> |

7. Marking

Table 4. Marking codes

| Type number | Marking code[1] |
|-------------|-----------------|
| PMP5201Y-Q | S9% |

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------|-------------------------------------|-----|-----|------|------|
| Per transistor | • | | , | | | |
| V_{CBO} | collector-base voltage | open emitter | | - | -50 | V |
| V_{CEO} | collector-emitter voltage | open base | | - | -45 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | -5 | V |
| I _C | collector current | | | - | -100 | mA |
| I _{CM} | peak collector current | t _p ≤ 1 ms; single pulse | | - | -200 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 200 | mW |
| Per device | | | | | | |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 300 | mW |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -65 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------|---|-------------|-----|-----|-----|-----|------|
| Per transist | or | | , | | | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | [1] | - | - | 625 | K/W |
| Per device | | | | ' | | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | [1] | - | - | 416 | K/W |

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|------------------------------------|---------------------------------|---|-----|------|------|------|------|
| Per transisto | or | | | ' | ' | ' | ' |
| I _{CBO} | collector-base cut-off | V _{CB} = -30 V; I _E = 0 A; T _{amb} = 25 °C | | - | - | -15 | nA |
| | current | V _{CB} = -30 V; I _E = 0 A; T _j = 150 °C | | - | - | -5 | μA |
| I _{EBO} | emitter-base cut-off current | V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C | | - | - | -100 | nA |
| h _{FE} | DC current gain | V _{CE} = -5 V; I _C = -10 μA; T _{amb} = 25 °C | | - | 250 | - | |
| | | V_{CE} = -5 V; I_{C} = -2 mA; T_{amb} = 25 °C | | 200 | 290 | 450 | |
| V _{CEsat} | collector-emitter | I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C | | - | -50 | -200 | mV |
| | saturation voltage | I_C = -100 mA; I_B = -5 mA; $\delta \le 0.02$; T_{amb} = 25 °C | | - | -200 | -400 | mV |
| V _{BEsat} | base-emitter saturation voltage | I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C | [1] | - | -760 | - | mV |
| İ | | I_C = -100 mA; I_B = -5 mA; T_{amb} = 25 °C | [1] | - | -920 | - | mV |
| V _{BE} | base-emitter voltage | V_{CE} = -5 V; I_{C} = -2 mA; T_{amb} = 25 °C | [2] | -600 | -650 | -700 | mV |
| | | V_{CE} = -5 V; I_{C} = -10 mA; T_{amb} = 25 °C | [2] | - | - | -760 | mV |
| C _c | collector capacitance | V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C | | - | - | 2.2 | pF |
| C _e | emitter capacitance | V_{EB} = -0.5 V; I_{C} = 0 A; i_{c} = 0 A; f = 1 MHz; f_{amb} = 25 °C | | - | 10 | - | pF |
| f _T | transition frequency | V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C | | 100 | 175 | - | MHz |
| NF | noise figure | V_{CE} = -5 V; I_{C} = -0.2 mA; R_{S} = 2 k Ω ; f = 10 Hz to 15.7 kHZ; T_{amb} = 25 °C | | - | 1.6 | - | dB |
| | | V_{CE} = -5 V; I_{C} = -0.2 mA; R_{S} = 2 k Ω ; f = 1 kHz; B = 200 Hz | | - | 3.1 | - | dB |
| Per device | 1 | , | 1 | 1 | 1 | 1 | |
| h _{FE1} /h _{FE2} | DC current gain matching | V_{CE} = -5 V; I_{C} = -2 mA; T_{amb} = 25 °C | | 0.98 | 1 | 1.02 | |
| V _{BE1} -V _{BE2} | base-emitter voltage matching | | | -2 | - | 2 | mV |

 V_{BEsat} decreases by about 1.7 mV/K with increasing temperature. V_{BE} decreases by about 2 mV/K with increasing temperature.

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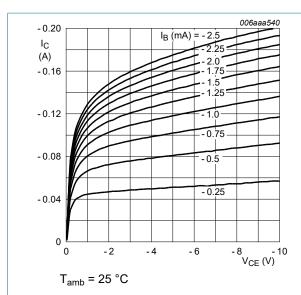
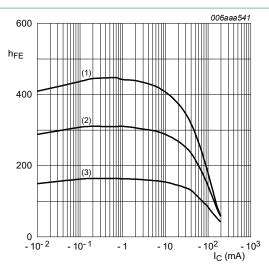
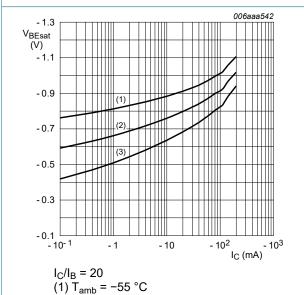


Fig. 1. Per transistor: Collector current as a function of collector-emitter voltage; typical values



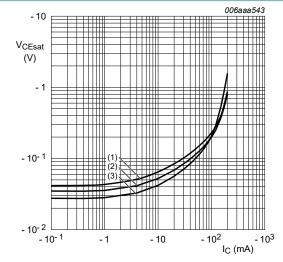
V_{CE} = -5 V (1) T_{amb} = 100 °C (2) T_{amb} = 25 °C (3) T_{amb} = -55 °C

Fig. 2. Per transistor: DC current gain as a function of collector current; typical values



(3) T_{amb} = 100 °C
Fig. 3. Per transistor: Base-emitter saturation voltage as a function of collector current; typical values

(2) T_{amb} = 25 °C

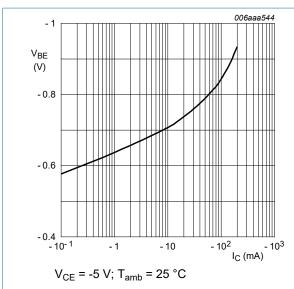


 $I_{\rm C}/I_{\rm B} = 20$ (1) $T_{\rm amb} = 100~{\rm ^{\circ}C}$ (2) $T_{\rm amb} = 25~{\rm ^{\circ}C}$ (3) $T_{\rm amb} = -55~{\rm ^{\circ}C}$

Fig. 4. Per transistor: Collector-emitter saturation voltage as a function of collector current; typical values

10³

45 V, 100 mA PNP/PNP matched double transistor



Per transistor: Base-emitter voltage as a function of collector current; typical values

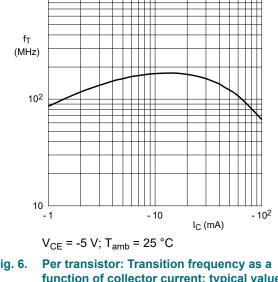
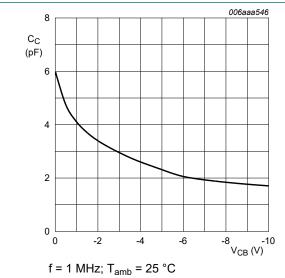


Fig. 6. function of collector current; typical values



Per transistor: Collector capacitance as a function of collector-base voltage; typical

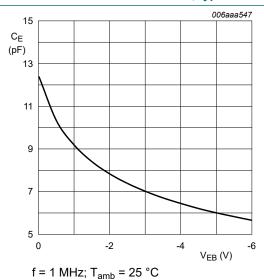
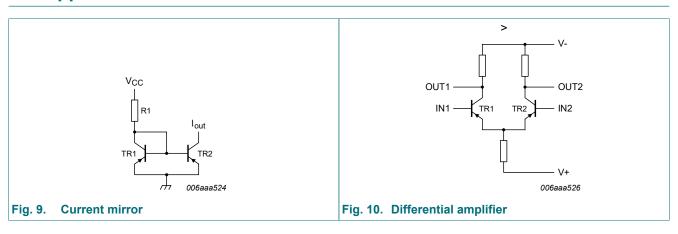


Fig. 8. Per transistor: Emitter capacitance as a function of emitter-base voltage; typical values

11. Application information



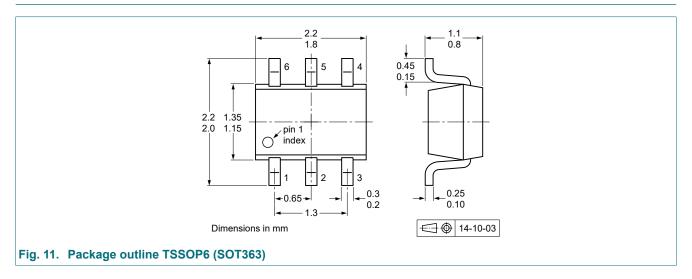
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12. Test information

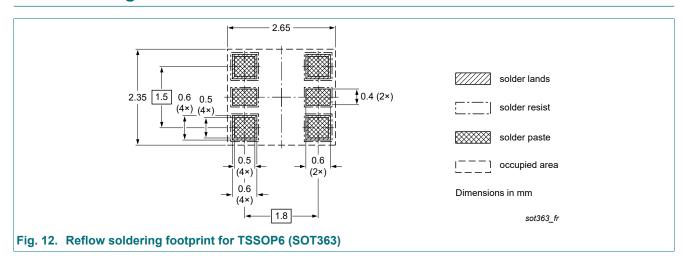
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

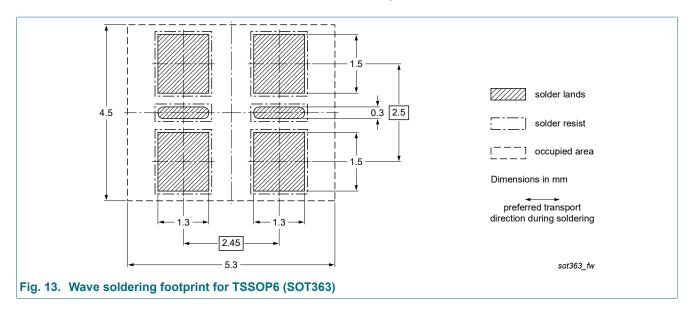
13. Package outline



14. Soldering



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15. Revision history

Table 8. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | | |
|----------------|--|--------------------|---------------|----------------|--|--|
| PMP5201Y-Q v.2 | 20220831 | Product data sheet | - | PMP5201Y-Q v.1 | | |
| Modifications: | Subtitle revisedSection "Application information" added | | | | | |
| PMP5201Y-Q v.1 | 20220629 | Product data sheet | - | - | | |

16. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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Date of release: 31 August 2022

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